DESCRIPTION

- With TO-220F package
- High breakdown voltage
- High speed switching performance

APPLICATIONS

- For switching regulator and general purpose power amplifier applications

PINNING

PIN	DESCRIPTION
1	Base
2	Collector
3	Emitter

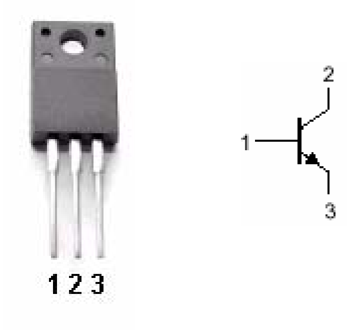

Fig.1 simplified outline (TO-220F) and symbol

Absolute maximum ratings (Ta=25℃)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage	Open emitter	500	V
V_{CEO}	Collector-emitter voltage	Open base	400	V
V_{EBO}	Emitter-base voltage	Open collector	7	V
I_C	Collector current		5	A
P_C	Collector dissipation	T_C=25℃	40	W
T_j	Junction temperature		150	℃
T_{stg}	Storage temperature		-55~150	℃

CHARACTERISTICS

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-emitter sustainig voltage	I_C=100mA ; I_B=0	400			V
$V_{(BR)CBO}$	Collector-base breakdown voltage	I_C=1mA ; I_E=0	500			V
$V_{(BR)EBO}$	Emitter-base breakdown voltage	I_E=1mA ; I_C=0	7			V
V_{CEsat}	Collector-emitter saturation voltage	I_C=2A ;I_B=0.4A			0.8	V
V_{BEsat}	Base-emitter saturation voltage	I_C=2A ;I_B=0.4A			1.2	V
I_{CBO}	Collector cut-off current	V_{CB}=450V; I_E=0			100	μ A
I_{EBO}	Emitter cut-off current	V_{EB}=7V; I_C=0			100	μ A
h_{FE-1}	DC current gain	I_C=0.5A ; V_{CE}=5V	25		65	
h_{FE-2}	DC current gain	I_C=2A ; V_{CE}=5V	20			

PACKAGE OUTLINE

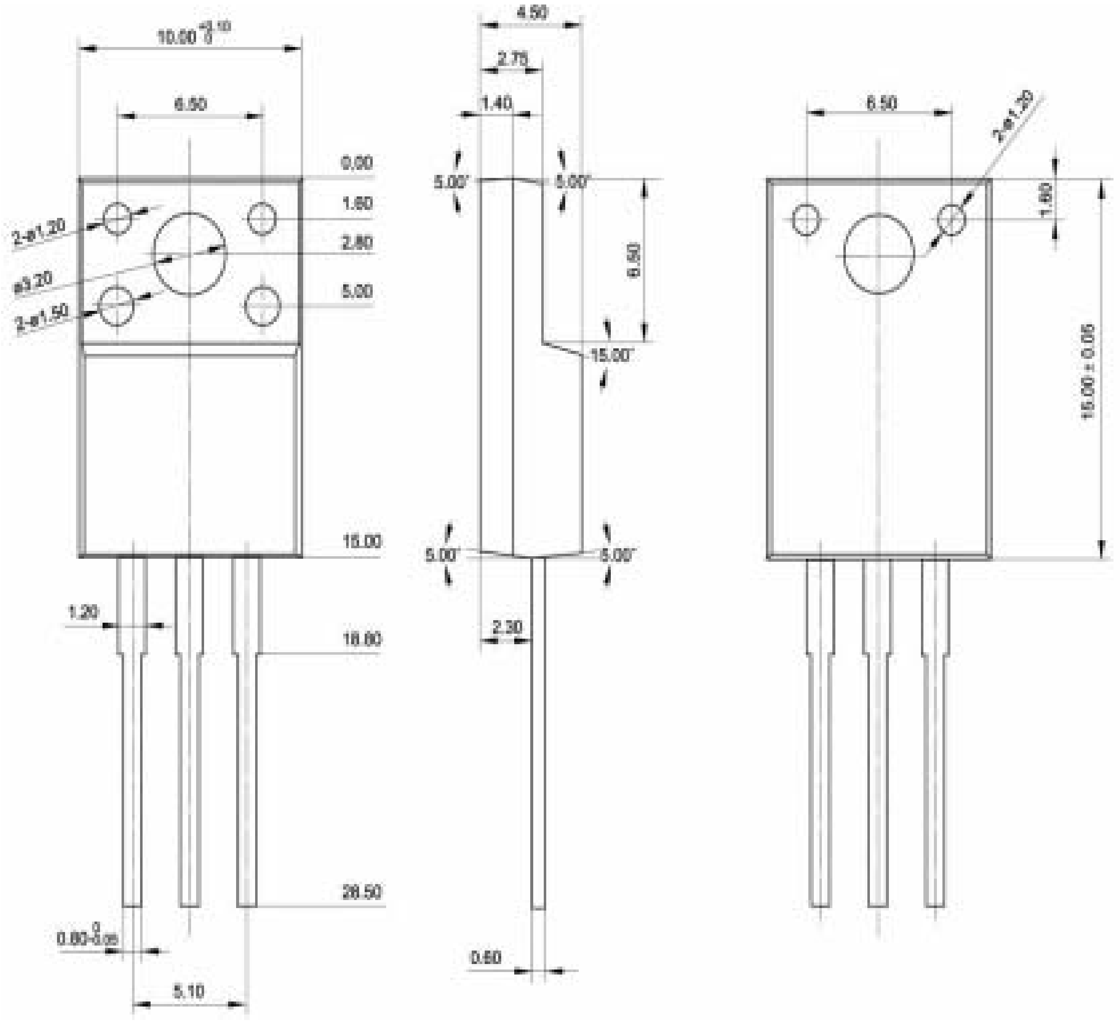

Fig.2 Outline dimensions